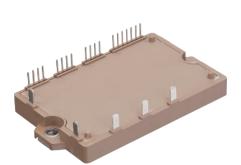


IGBT Modules

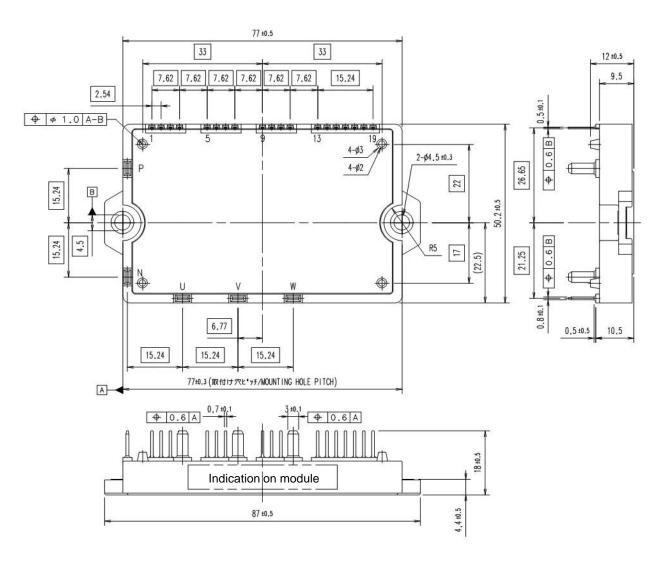
IGBT Module (X series) 1200V / 35A / IPM

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- ·Low power loss and soft switching
- · High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of
- parts in built-in control circuit



Outline drawing (Unit : mm)



Weight:100g(typ.)

F Fuji Electric 6MBP35XBA120-50

IGBT Modules

Absolute maximum ratings

-25°C T -25°C V =15V unless otherwise specified

7 _C =25°C, 7 _{vj} =25°C, V _{CC} =15∖ Item	Symbol	Conditions	Min.	Max.	Units
Collector-Emitter voltage	V _{CES}	*1	-	1200	V
Short circuit voltage	V _{SC}	*2	400	800	V
, ir	I _C	DC	-	35	Α
	I _{CP}	1ms	-	70	Α
9 AL	-/ _c	Duty=100% *3	-	35	Α
Total power dissipation	P _{tot}	IGBT 1 device *4	-	245	W
Dellector current	I _c	DC	-	-	Α
	I _{CP}	1ms	-	-	Α
E Forward current of diode	/ _F		-	-	Α
Total power dissipation	P_{tot}	IGBT 1 device *4	-	-	W
Supply voltage of pre-driver	V _{cc}	*5	-0.5	20	V
Input signal voltage	V _{in}	*6	-0.5	V _{CC} +0.5	V
Alarm signal voltage	V _{ALM}	*7	-0.5	V _{CC}	V
Alarm signal current	I _{ALM}	*8	-	20	mA
T _{vi} Warning signal voltage	V _{WNG}	*9	-0.5	V _{CC}	V
T _{vj} Warning signal current	/ _{WNG}	*10	-	20	mA
Virtual junction temperature	T _{vj}		-	175	°C
Operating virtual junction temperatu	re T _{vjop}		-	150	°C
Operating case temperature	T _c		-20	125	°C
Storage temperature	T _{stg}		-40	125	°C
Solder temperature	T _{sol}	*11	-	260	°C
Isolating voltage	V _{isol}	*12	-	2500	Vrms
Mounting torque of screws to heat s	ink M _s	Mounting(M4)	-	1.7	Nm
Mounting torque of screws to termin Notes		Main terminals(M4)	-	-	Nm

Notes

*1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W)-N.

*2: In the case of the load inductance to be over 1µH.

*3: Duty=150°C/ $R_{th(i-c)D}/(I_F \times V_F Max.) \times 100$

*4: $P_{tot}=150^{\circ}C/R_{th(i-c)Q}$ *5: V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13.

*6: V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 16~18 and 13.

*7: V_{ALM} shall be applied to the voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 19 and 13.

*8: I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

*9: V_{WNG} shall be applied to the voltage between terminal No.15 and 13.

*10: I_{WNG} shall be applied to the input current to terminal No.15.

*11: Immersion time 10±1sec. 1 time.

*12: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

Electrical characteristics

Main circuit

 $T_{\rm w}=25^{\circ}C$ $V_{\rm co}=15V$ unless otherwise specified

	r_{vi} -25 C, v_{CC} - 15 V unlet Item	Symbol		nditions	Min.	Typ.	Max.	Units
er -	Collector current at off signal input	I _{CES}	V _{CE} = 1200V	nations	-	-	1.0	mA
Inverter	Collector-Emitter	$V_{\text{CE(sat)}}$	1 _c = 35A	Terminal	-	-	1.80	V V
2	saturation voltage		I _F = 35A	Chip Terminal	-	1.40 -	- 2.45	V
	Forward voltage of FWD	V _F		Chip	-	2.00	-	V
	Collector current at off signal input	I _{CES}			-	-	-	mA
Brake	Collector-Emitter saturation voltage	$V_{ ext{CE(sat)}}$		Terminal Chip	-	-	-	V V
	Forward voltage of FWD	V		Terminal	-	-	-	V
	Forward vollage of FWD	V _F		Chip	-	-	-	V
	hing time	$t_{\sf on}$	I _c = 35A	T_{vi} =150°C	0.5	-	-	μs
*13		$t_{d(on)}$	$V_{\rm DC} = 600 V$		0.5	-		μs
		$t_{ m off}$			-	-	2.0	μs
		$t_{d(off)}$			-	-	1.7	μs
		t _{rr}	I _F = 35A V _{DC} = 600V	T _{vi} =150°C	-	-	0.5	μs

*13: Turn on time $(t_{on}) = t_{d(on)} + t_{r}$, Turn off time $(t_{off}) = t_{d(off)} + t_{f}$



IGBT Modules

Control circuit

 T_{vj} =25°C, V_{CC} =15V unless otherwise specified

ltem	Symbol	Conditions		Min.	Тур.	Max.	Units
Supply current of P-side	1	Switching frequency $(f_{SW}) = 0 \sim$	15kHz	-	-	10	mA
pre-driver (per one unit)	I ccp	T _C = -20∼125°C					
Supply current of N-side	1			-	-	26	mA
pre-driver	/ ccn						
Input signal threshold voltage	V _{inth(on)}	V _{in} -GND	ON	1.2	1.4	1.6	V
Input signal threshold voltage	$V_{\text{inth(off)}}$	V in-GND	OFF	1.5	1.7	1.9	V

Protection circuit

 T_{vi} =25°C, V_{CC} =15V unless otherwise specified

Item	۱	Symbol	Conditions	Min	Тур.	Max.	Units
Over current	Inverter	I _{oc}	T _{vj} =150°C	53	-	-	Α
protection level	Brake	100		-	-	-	Α
Over current protectior	n delay time	t _{dOC}	T _{vj} =150°C	-	4.0	-	μs
Short circuit protection	delay time	t _{dSC}	T _{vi} =150°C	-	1.0	-	μs
IGBT chips over heatir protection temperature		Т _{јОН}	Surface of IGBT chips	175	-	-	°C
Over heating protection	n hysteresis	T _{jH}		-	20	-	°C
IGBT chips warning te	mperature level	T _{jW}	Surface of IGBT chips (Y)	150	-	-	
Warning hysteresis		T _{iWH}		-	10	-	
Under voltage protection	on level	V _{UV}		11.0) –	12.5	V
Under voltage protection	on hysteresis	V _H		0.2	0.5	-	V
Alarm signal hold time		$t_{ALM(OC)}$ $t_{ALM(UV)}$	ALM-GND] <i>T</i> _C =-20 ~ 125°C	1.0 10V 3.5	2.0	2.4 4.5	ms ms
		t _{ALM(TjOH)}		7.0	8.0	9.0	ms
Warning signal hold tir	ne	t _{WNG}	WNG-GND <i>T</i> _c =-20~125°C		operati ancella		ms
Alarm signal voltage		V _{ALMH}	ALM-GND, without protection	14.5	5 -	15.0	V
Warning signal voltage	9	V_{WNGH}	WNG-GND, without warning	14.5	j -	15.0	V
Resistance for current	limit	R_{ALM}		960	-	1570	Ω
		$R_{\rm WNG}$		960	-	1570	Ω

■ Thermal resistance characteristics (*T*_c = 25°C)

ltem		Symbol	Min.	Тур.	Max.	Units	
Thermal resistance Inverter		IGBT	$R_{\rm th(i-c)Q}$	-	-	0.61	K/W
junction to case	Inverter	FWD	$R_{\rm th(i-c)D}$	-	-	0.94	K/W
,	Brake	IGBT	$R_{\rm th(j-c)Q}$	-	-	-	K/W
*14	DIAKE	FWD	$R_{\rm th(i-c)D}$	-	-	-	K/W
Thermal resistance case	Thermal resistance case to heat sink *15		$R_{\rm th(c-s)}$	-	0.05	-	K/W

*14: For 1 device , the measurement point of the case is just under the chip.

*15: This is the value which is defined mounting on the additional heat sink with 1 W/($m \cdot K$) thermal grease.

■ Noise immunity (V_{DC} =600V, V_{CC} =15V)

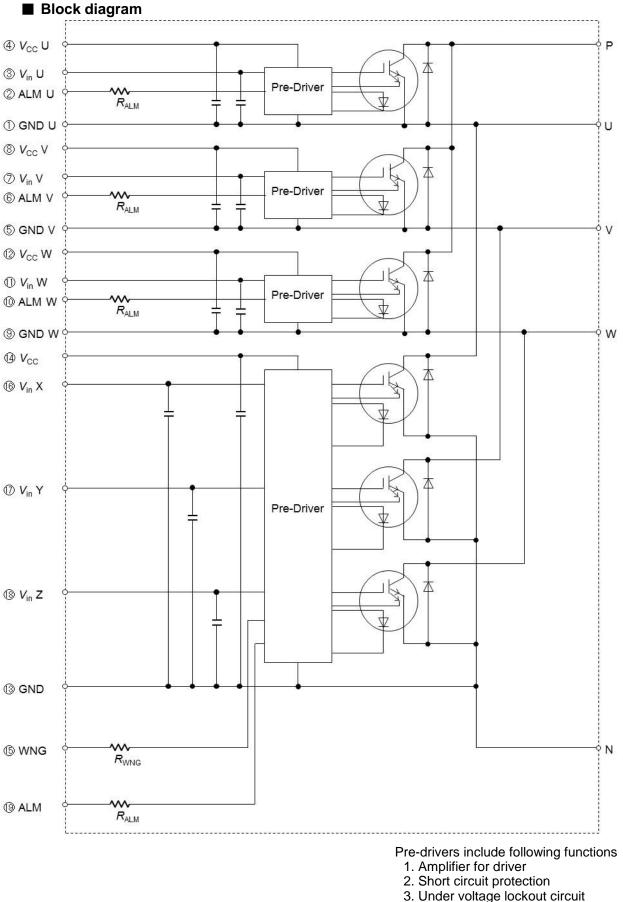
Item	Conditions	Min.	Тур.	Max.	Units
Common mode	Pulse width 1µs,polarity ±,10min.	±2.0			kV
rectangular noise	Judge: no over-current, no miss operating	±2.0	-	-	κv

Recommended operating conditions

Symbol	Min.	Тур.	Max.	Units
V_{DC}	-	-	800	V
V _{cc}	13.5	15.0	16.5	V
f _{sw}	-	-	20.0	kHz
$t_{\sf dead}$	1.5	-	-	μs
-	1.3	-	1.7	Nm
		$ \begin{array}{c c} V_{DC} & - \\ V_{CC} & 13.5 \\ \hline f_{SW} & - \\ \hline t_{dead} & 1.5 \end{array} $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

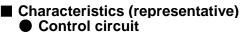
*16: $t_{dead} = t_{off} - t_{d(on)}$

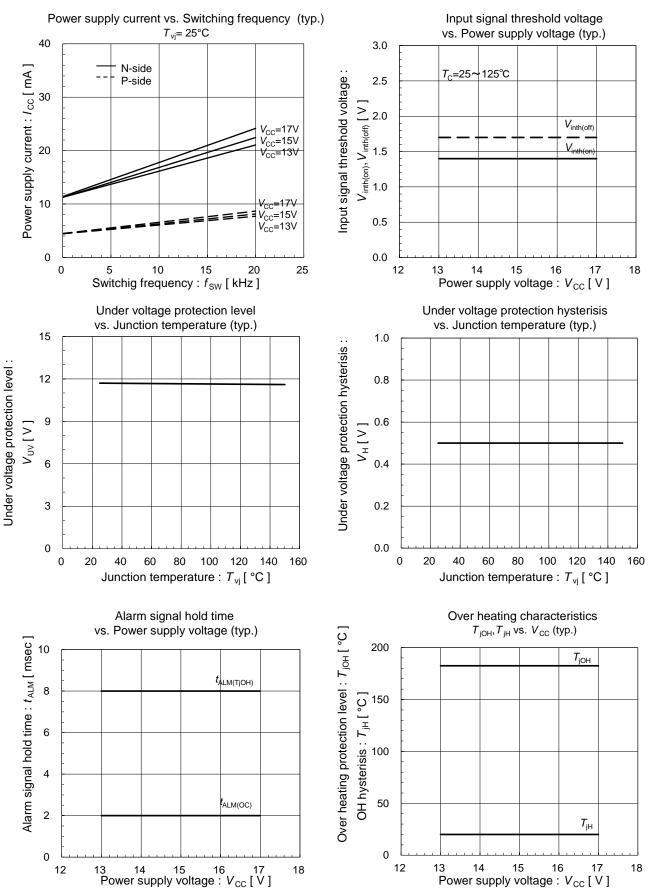




- 4. Over current protection
- 5. IGBT chip over heating protection

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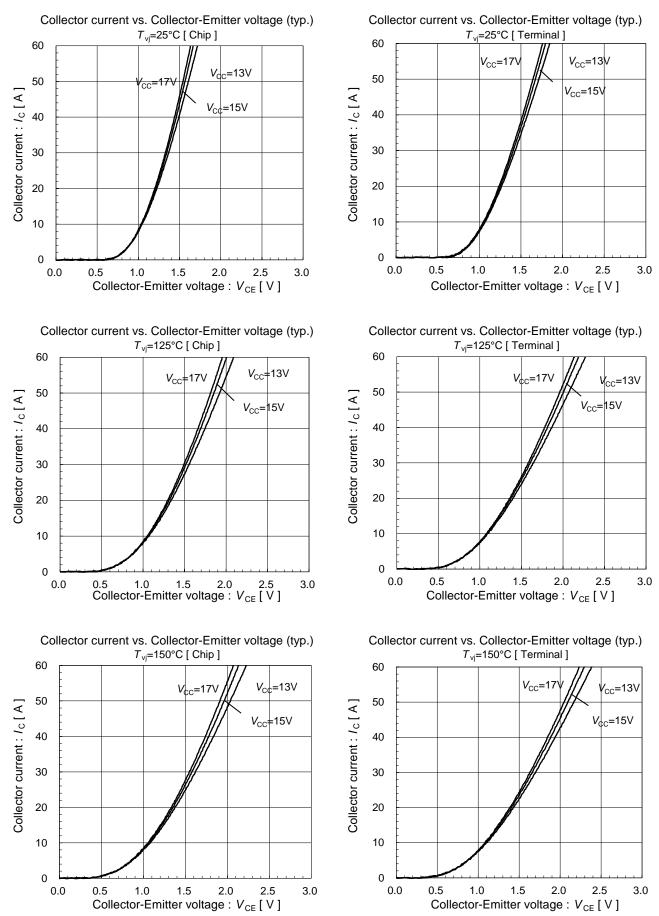




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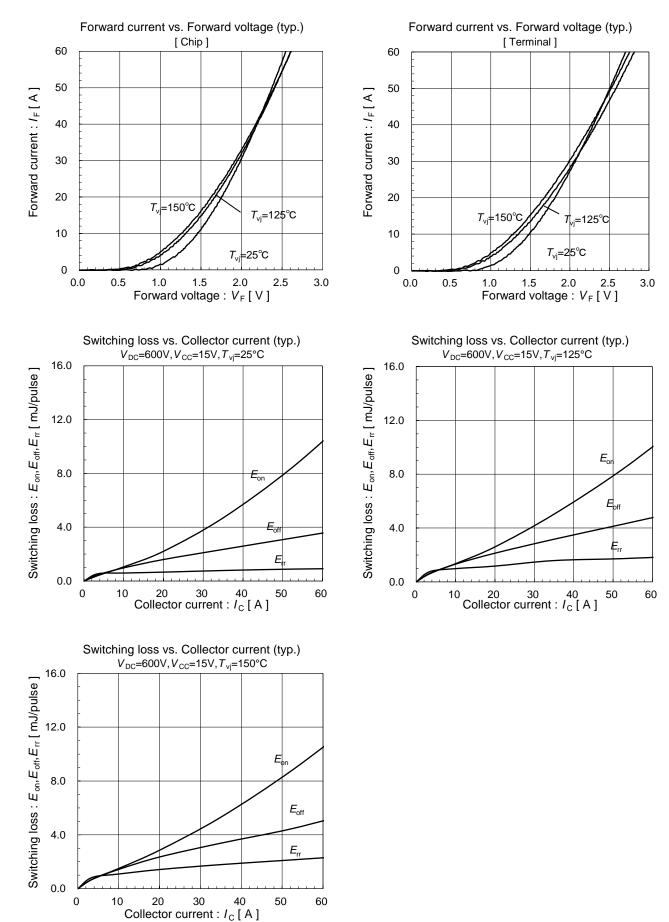
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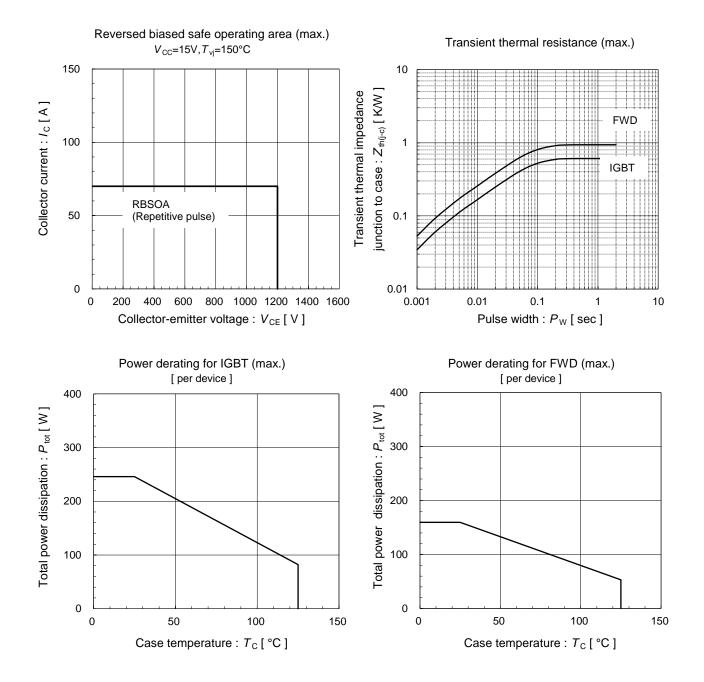


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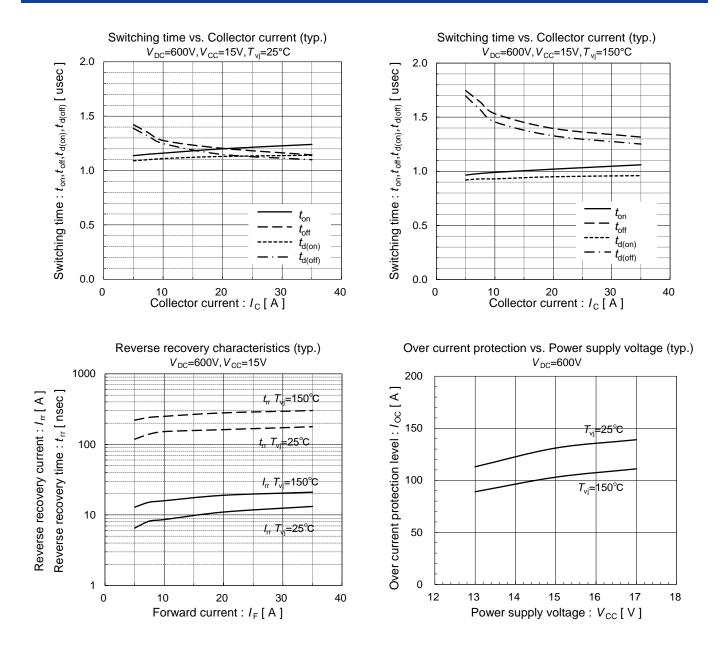




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6MBP35XBA120-50

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